

N-Channel Super Junction Power MOSFET $\ensuremath{\,\mathrm{IV}}$

General Description

The series of devices use advanced trench gate super junction technology and design to provide excellent R_{DS(ON)} with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

Features

- •New technology for high voltage device
- Low on-resistance and low conduction losses
- Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- 100% Avalanche Tested
- ●ROHS compliant

Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

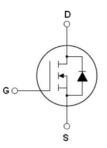
Package Marking And Ordering Information

Device	Device Package	Marking
NCE50NF330I	TO-251-3L	NCE50NF330I

Table 1. Absolute Maximum Ratings (Tc=25℃)

Parameter	Symbol	Value	Unit
Drain-Source Voltage (VGs=0V)	VDS	500	V
Gate-Source Voltage (VDS=0V) ,AC (f>1 Hz)	Vgs	±30	V
Gate-Source Voltage (VDs=0V) ,DC	Vgs	±20	V
Continuous Drain Current at Tc=25°C	I _{D (DC)}	10	A
Continuous Drain Current at Tc=100°C	I _{D (DC)}	7	A
Pulsed drain current ^(Note 1)	DM (pluse)	30	A
Maximum Power Dissipation(Tc=25°C)	PD	93	W
Derate above 25°C		0.62	W/°C
Single pulse avalanche current (Note 2)	I _{AS}	2.5	A
Reverse diode dv/dt, $V_{DS} \leqslant 480 \text{ V},I_{SD} < I_D$	dv/dt	15	V/ns
Drain Source voltage slope, $V_{DS} \leqslant 480 V$	dv/dt	50	V/ns
Operating Junction and Storage Temperature Range	TJ,TSTG	-55+175	°C

V _{DS min@Tjmax}	550	V
Rds(on)typ.	280	mΩ
ID	10	А
Qg	12.5	nC



Schematic diagram

♦ Intrinsic fast-recovery body diode





Table 2. Thermal Characteristic

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (Maximum)	R _{thJC}	1.61	°C /W
Thermal Resistance, Junction-to-Ambient (Maximum)	R _{thJA}	62	°C /W

Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
On/off states				-	I	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250uA	500			V
Zero Gate Voltage Drain Current(Tc=25°C)	I _{DSS}	V _{DS} =500V,V _{GS} =0V			10	μA
Zero Gate Voltage Drain Current(Tc=125°C)	I _{DSS}	V _{DS} =500V,V _{GS} =0V			300	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V			±200	nA
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	3		5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10V, I_{D} =5A		280	330	mΩ
Dynamic Characteristics					· · · ·	
Gate Resistance	Rg	F=1MHZ, D-S short		37		Ω
Input Capacitance	Clss			545		pF
Output Capacitance	Coss	V _{DS} =50V,V _{GS} =0V, F=1MHz		36		pF
Reverse Transfer Capacitance	C _{rss}			4		pF
Total Gate Charge	Qg			12.5	15.5	nC
Gate-Source Charge	Q _{gs}	V _{DS} =400V,I _D =5A,		5		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V		3.5		nC
Gate plateau voltage	Vgp			6.5		V
Switching times						
Turn-on Delay Time	t _{d(on)}			9		nS
Turn-on Rise Time	tr	V_{DD} =380V,I _D =5A, R _G =4Ω,V _{GS} =10V		12		nS
Turn-Off Delay Time	t _{d(off)}			43		nS
Turn-Off Fall Time	t _f			10		nS
Source- Drain Diode Characteristics						
Source-drain current(Body Diode)	I _{SD}	Tc=25°C			10	А
Pulsed-Source-drain current(Body Diode)	I _{SDM}				30	А
Forward on voltage	V _{SD}	Tj=25°C,I _{SD} =10A,V _{GS} =0V		1.0	1.2	V
Reverse Recovery Time	t _{rr}	Tj=25°C,IF5A,		135		nS
Reverse Recovery Charge	Q _{rr}			0.37		uC
Peak reverse recovery current	Irrm	di/dt=100A/µs		5.5		А

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25 $^\circ\!\mathrm{C}$,VDD=50V,VG=10V, R_G=25 Ω



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Output characteristics

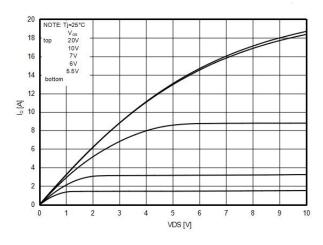


Figure3. R_{DS(ON)} vs Junction Temperature

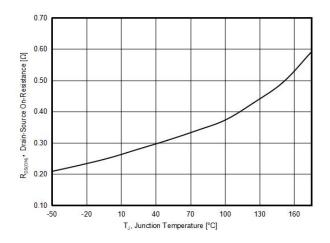


Figure 5. Maximum I_D vs Junction Temperature

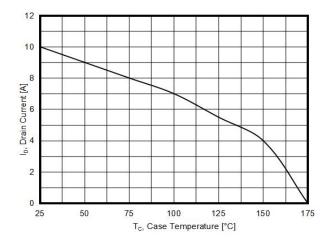


Figure2. Transfer characteristics

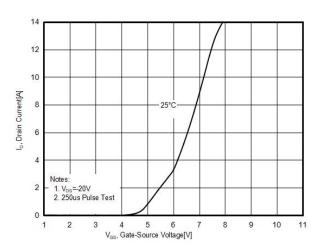


Figure4. BV_{DSS} vs Junction Temperature

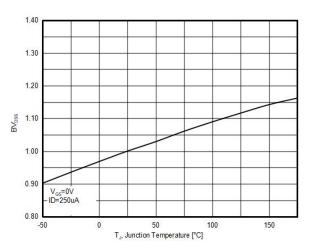


Figure6. Gate charge waveforms

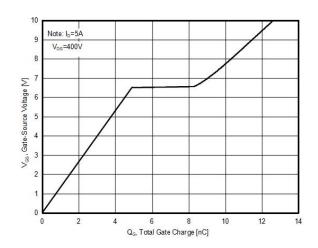




Figure7. Static drain-source on resistance

Figure8. Source-Drain Diode Forward Voltage

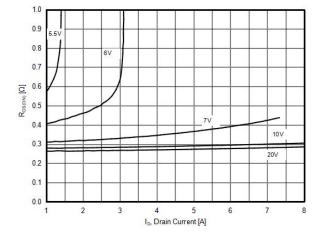
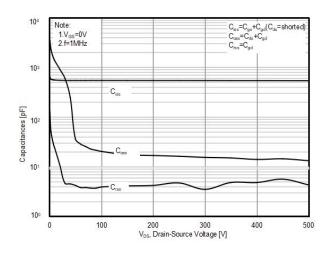


Figure9. Capacitance



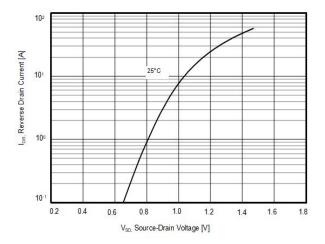
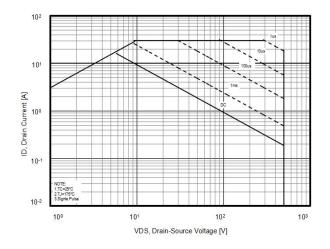


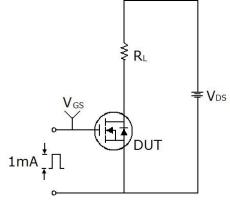
Figure10. Safe operating area

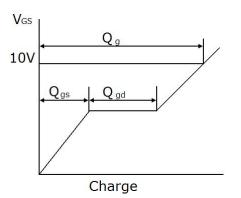




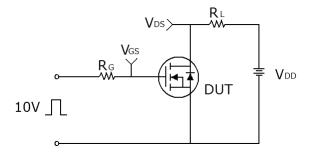
Test circuit

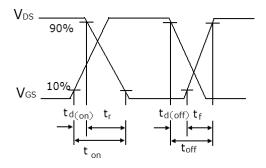
1) Gate charge test circuit & Waveform



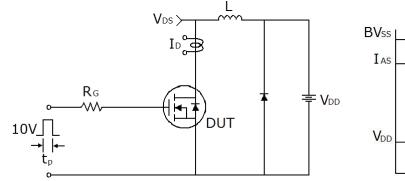


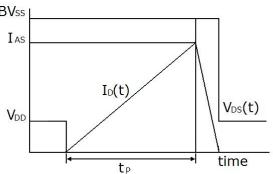
2) Switch Time Test Circuit:





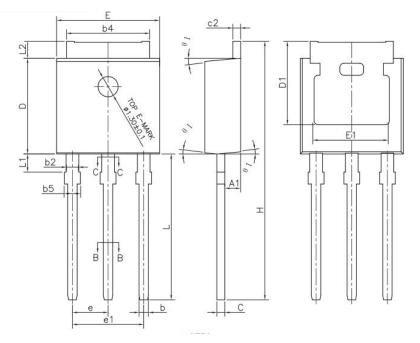
3) Unclamped Inductive Switching Test Circuit & Waveforms







TO-251-3L-P Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	2.20	2.35	0.087	0.093	
A1	0.90	1.10	0.035	0.043	
b	0.56	0.69	0.022	0.027	
b1	0.55	0.65	0.022	0.026	
b2	0.77	0.90	0.030	0.035	
b3	0.76	0.86	0.030	0.034	
b4	5.23	5.43	0.206	0.214	
b5		1.05		0.041	
С	0.46	0.59	0.018	0.023	
c1	0.45	0.55	0.018	0.022	
c2	0.46	0.59	0.018	0.023	
D	6.00	6.20	0.236	0.244	
D1	5.20		0.205		
E	6.50	6.70	0.256	0.264	
E1	4.60	5.00	0.181	0.197	
e	2.24	2.34	0.088	0.092	
e1	4.47	4.67	0.176	0.184	
Н	16.18	16.78	0.637	0.661	
L	9.00	9.60	0.354	0.378	
L1	0.95	1.35	0.037	0.053	
L2	0.90	1.25	0.035	0.049	



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